## Two-Electron Linear Intersubband Light Absorption in a Biased Quantum Well

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We point out a novel manifestation of many-body correlations in the linear optical response of electrons con ned in a quantum well. Namely, we demonstrate that along with conventional absorption peak at frequency ! close to intersubband energy , there exists an additional peak at frequency ~! 2 . This new peak is solely due to electron-electron interactions, and can be understood as excitation of two electrons by a single photon. The actual peak lineshape is com prised of a sharp feature, due to excitation of pairs of intersubband plasm ons, on top of a broader band due to absorption by two single-particle excitations. The two-plasm on contribution allows to infer intersubband plasm on dispersion from linear absorption experiments.

Introduction | Intersubband absorption of light in a quantum well (QW) is studied theoretically and experimentally form one than two decades. O riginalm otivation for such a close attention to this process was its crucial role in design of infrared detectors [1]. Lately, the interest in intersubband transitions is spurred by advances in fabrication of the quantum cascade lasers [2].

W ithin a single-electron description and in the absence of nonparabolicity, the intersubband absorption peak is in nitely narrow and positioned precisely at ~! = where  $= E_2$   $E_1$  is the intersubband separation (see Fig.1). A selectron-electron interactions are switched on, the adequate language for the description of absorption becomes the excitations of intersubband plasmon (ISP) by light polarized perpendicular to the QW plane. M anybody origin of the absorption manifests itself in a shift of peak position up from ~! = (depolarization shift), and nite peak width even at zero tem perature and in the а absence of disorder. W hile the shift has been understood long ago [3, 4, 5], the interaction-induced broadening of the absorption line still remains a subject of debate. The peak lineshape was addressed in several recent studies that employed various approximate many-body schemes, and yielded lineshapes calculated num erically for particular sets of QW parameters [6, 7, 8, 9, 10, 11]. The lack of analytical description (even in the lim it of weak interactions) re ects the fact that the peak lineshape is governed by very delicate correlations in 2D electron gas.

In the present paper we point out that, in addition to conventional intersubband absorption, there exists a distinctive interaction-induced e ect, namely, two-particle linear absorption of light. O bviously, without interactions, one photon can excite only one electron from the lower to the upper subband. This is the case even in the presense of disorder that violates momentum conservation. Our main point is that interactions allow a photon with energy ~! 2 to excite simultaneously two intersubband excitations (single-particle or collective). As a result, the absorption peak is comprised of a sharp feature originating from excitation of two ISPs on top of a broader band of two single-particle excitations. W e show that absorption of a photon by two single-particle excitations can be captured perturbatively in the interaction

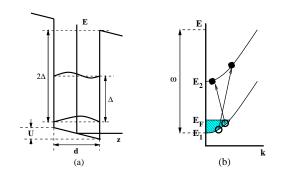


FIG.1: (a) Two lowest size-quantization wave functions of a biased quantum wellare shown schematically; for two-electron linear absorption, the incident photon energy must be close to  $2 \cdot (b)$  Two-electron intersubband absorption in the lowest order of the perturbation theory.

strength. By contrast, in order to describe two-plasm on absorption, a nonperturbative approach is required. Such an approach is developed in this paper.

A rem arkable feature of two-particle absorption is that the ISP dispersion  $!_{p1}(q)$  at nite momenta can be inferred from the peak shape. Indeed, with two nitemomentum ISPs in the nal state, the momentum conservation can be respected even though the momentum of an incident photon is negligible [12]. A nother distinctive feature of the 2 peak is its sensitivity to external bias, U, applied across QW; for a symmetric QW, the 2 peak emerges only at nite U and grows as  $U^2$ .

Form alism | The proposed e ect is most naturally described in diagram matic language. The conventional absorption is represented by standard polarization bubble see Fig. 2(a). Dipole matrix elements  $z_{12} = \frac{1}{2} z'_2 dz$  in the vertices are responsible for promotion of an electron from subband 1 to subbband 2 (see Fig. 1), where  $\frac{1}{1}$ ,  $\frac{2}{2}$  are the size-quantization wavefunctions. Since the momentum of photon is negligibly small, the intersubband polarization operator is simply  $P_0$  (!) =  $\frac{N}{2}$ , where  $N = \frac{k_F^2}{2}$  is electron concentration and  $k_F$  is the Ferm i momentum. We assume that the Ferm i energy  $E_F = \frac{z^2 k_F^2}{2m}$  is smaller than (here m is the electron)

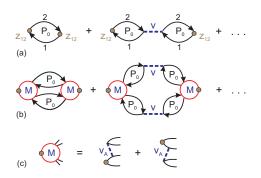


FIG. 2: Diagram m atic representation of single-particle absorption (a), two-particle absorption (b) and two-electron dipole m atrix element (c).  $V_A$  stands for  $V_{1222}$  and  $V_{1211}$  in rst and second digram, respectively.

m ass). As explained above, the adequate picture of absorption is excitation of ISP (rather than electron-hole pair). D iagram m atically see Fig. 2 (a) this is accom – plished by a standard RPA sum m ation of polarization bubbles connected by intersubband C oulom b m atrix element, V  $V_{1212}$  (0); we adopt the standard de nition of m atrix elements Z

$$V_{ijk1}(q) = v_{q} \quad dz dz^{0\prime}_{i}(z)'_{j}(z^{0})'_{k}(z^{0})'_{1}(z)e^{-q'z - \frac{\beta}{2}j}; (1)$$

where  $v_q = \frac{2}{q} \frac{e^2}{q}$  is the Fourier component of 2D C oulom b potential and is the dielectric constant. For a rectangular well, we have  $V_{1212}(0) = _0 = ,$  where  $= m = -^2$ is the 2D density of states, while the dimensionless param eter  $_0$  is given by

$$_{0} = \frac{10}{9} r_{s}^{p} \overline{6E_{F}} = ;$$
 (2)

where  $r_s = \frac{p}{2m} e^2 = -k_F$  is the interaction parameter. The RPA summation amounts to a replacement of  $P_0$  by the ISP propagator  $= P_0 (1 - V_{1212}P_0)^{-1}$ . It is important that at q = 0 the propagator  $(!) = \frac{N}{! - \frac{N}{V_{1212}N}}$  has the same form as  $P_0 (!)$  except for the depolarization shift of the pole position [3, 4, 5]. Thus, within RPA, the entire oscillator strength is simply transferred to ISP.

It is convenient to explain the novel absoption peak at ! 2 by building on analogy to Fig.2(a). The corresponding diagram s are presented in Fig.2(b). The vertices  $M_q$  now stand for matrix elements that transform a photon into two intersubband electron-hole (e-h) pairs. Each electron (hole) propagator in Fig.2(a) is now replaced by double line (one electron and one hole). All four lines begin (and end) at the same vertex.

It is obvious that, without interactions, M  $_q$  is identically zero. This is the case even in the presence of disorder and relects the orthogonality of eigenstates in QW. O urprime observation is that interactions give rise to a nite M  $_q$ . In the low est order in interactions, the diagram for M  $_q$  is shown in Fig.2 (c). The underlying virtual process can be described as follows. A photon with energy

! 2 rst creates an e-h pair by promoting an electron to the second subband. The electron from this pair subsequently undergoes intrasubband scattering, accompanied by excitation of intersubband e-h pair. The propagator of this pair is shown by the rst double-line emerging from the vertex  $M_q$  in Fig. 2 (b), while the second double-line corresponds to intrasubband-scattered photoexcited electron and photoexcited hole. Apparently, there is also a second contribution to  $M_q$ , originating from intrasubband scattering of the hole, as shown in Fig. 2 (c).

W e now turn to the higher-order diagram in Fig.2(b). In higher orders in interactions, each double-line, that represented a propagating e-h pair in the lowest-order diagram, is now replaced by ISP propagator. Such a dressing" is analogous to single-particle to collective excitation transform ation in the usual absorption [see Fig. 2(a)]. Correspondingly, the absorption coe cient has a general form

$$\begin{array}{c} X \\ {}_{2}(!) / ! \qquad M_{q} \stackrel{2}{f} J(!;q); \qquad (3) \\ q \end{array}$$

(we om itted a frequency-independent factor), where the joint spectral function J(!;q) is given by a convolution

$$J(!;q) = \frac{dE}{2} 2 \operatorname{Im} (E;q) 2 \operatorname{Im} (! E;q); \quad (4)$$

of two ISP propagators. Energy dependence of (E;q) com es from the free-electron intersubband polarization,

$$P_{0}(E;q) = 2 \frac{dp}{(2)^{2}} \frac{n_{1p}}{E + p} \frac{p+q+i0}{p+q+i0}$$

$$= \frac{q}{2q} E q (E q)^{2} (4E_{Fq}; 65)$$

where  $_{q} = \sim^{2}q^{2}=2m$  is electron dispersion,  $n_{1p}$  is the occupation of n = 1 subband, and the factor 2 accounts for spin. From the pole position of (E;q) at  $1 = V_{1212}$  (q)P<sub>0</sub> ( $_{p1}$ ;q), we obtain the ISP dispersion law,

$$\sim _{pl}(q) = \sim _{pl}(0) + (q _{0}) E_{F} + (1 + q^{1}) q;$$
 (6)

 $w \pm h \sim p_1(0) = + _0 E_F$  and  $_q = V_{1212}(q)$ , where  $V_{1212}$  (q) is de ned by Eq. 1). The bottom of the ISP band is shifted up by  ${}_{0}E_{F}$  from the intersubband separation . Note, that the full depolarization shift includes also the Hartree renorm alization of the intersubband separation, which has the same order of  $_{0}E_{F}$ . For parabolic QW this renorm alization insures that  $_{pl}(0) =$ in accordance with the Kohn theorem [5, 13]. For relevant momenta qd . 1, the q-dependence of the matrix elements, Vijkl, can be neglected, which leads to quadratic ISP dispersion:  $p_1(q) = q^2 = 2m_{p1}$ where  $m_{pl} = m_0 = (1 + _0)$  is the plasm on mass. Rem arkably, for  $E_F =$ 1, the plasm on is much lighter than the elctron,  $m_{pl}=m$ 0 1.

The ISP pointribution to J comes from the region  $E > 2 \overline{E_{Fq}} + q$  of the (E;q) plane, where the plasm on is not Landau-dam ped. Then, for the plasm on propagator, (E;q), one has 2 Im (E;q) =  $2 \text{ A}_q$  E ~  $_{pl}(q)$ , with the oscillator strength,  $A_q$ , given by

$$A_{q} = V_{1212} (q) \frac{@P_{0} (E;q)}{@E}_{E = p_{1}(q)}^{\# 1} = E_{F} \frac{q}{q} > 0:$$
(7)

U sing the fact that qd 1, we can set q = 0. Then the joint spectral function (8) acquires a simple form

$$J_{p1} = 2 {}^{2} E_{F} {}^{\frac{q}{2}} {}^{2} E_{F} {}^{\frac{q}{2}} {}^{2} E_{F} {}^{\frac{q}{2}} {}^{\frac{q}{2}} ! 2_{p1}(q); (8)$$

where the -function restricts them om enta to the dom ain where ISP is undam ped.

The contribution Eq. (8) comes from the poles of in the integrand of Eq. (4). For conventional intersubband absorption, Fig. 2(a), the pole contribution carries almost the entire oscillator strength. By contrast, Eq. (8) yields only an additional contribution to the joint spectral function, whereas the main contribution comes from the numerators of  $= P_0 = (1 \quad V_{1212}P_0)$  in Eq. (4). In calculating the latter, the denom inators can be set to 1, i.e., ISP s are damped in the corresponding dom ain of the (E;q) plane. In other words, the main contribution,

$$J_{ee} (!;q) = \frac{Z}{(2)^4} \frac{dk_1 dk_2}{n_{1k_1} n_{1k_2}}$$

$$8 \quad ! \quad 2 \qquad k_1 \quad q \quad k_2 + q + k_1 + k_2 ; (9)$$

is due to excitation of two e-h pairs rather than plasm ons and, being nonresonant, describes a broad plateau on which a sharp two-ISP peak resides.

Let us turn to the form of the two-electron matrix element M  $_{\rm q}$ . Analytical expression, corresponding to the sum of the diagram s in F ig. 2 (c), that describe possible channels of two-electron excitation, has the form

$$M_{q} = 2z_{12} \frac{V_{1222}(q) \quad V_{1211}(q)}{+ k_{1} \quad q + k_{2} + q \quad k_{1} \quad k_{2}} : \quad (10)$$

M inus sign in Eq. (10) originates from the di erence in energies of interm ediate states for the two channels. Note, that the momenta of the nal-state single-particle energies in the denom inator of Eq. (10) are restricted by energy conservation  $\sim ! = 2 + k_1 q + k_2 + q k_1 k_2$ . This relation ensures that the matrix element Eq. (10) depends only on the transferred momentum, q, so that

$$M_{q} = \frac{2z_{12}}{!} V_{1222} (q) V_{1211} (q) : (11)$$

Absorption  $\infty$  cient | It is convenient to express the two-electron absorption  $\infty$  cient,  $_2(!)$ , relative to the single-electron intersubband absorption,  $_1(!)$ . Nam ely, we introduce the ratio

$$\sim_{2} (!) = \frac{R_{2}(!)}{d!_{1}^{0}(!)} = \frac{2(!)}{2 E_{F} z_{12}^{2}}; \quad (12)$$

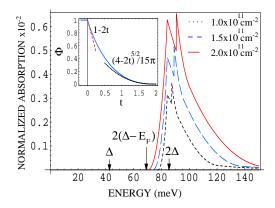


FIG.3: Normalized two-electron absorption, ~2, in d = 20 nm GaAsQW is shown for applied bias U = 30 meV and electron concentrations N =  $10^{11}$  cm<sup>2</sup>, 15  $10^{11}$  cm<sup>2</sup>, and 2.0  $10^{11}$  cm<sup>2</sup>. The right peak corresponds to two-plasm on absorption. A rrow indicates the position of single-electron absorption peak at . Inset: threshold behavior of two-electron absorption calculated from Eq. (15).

so that the area under the peak  $\sim_2$  (!) is equal to the ratio of the corresponding oscillator strengths. To proceed further, we note that the di erence,  $V_{1222}$  (q)  $V_{1211}$  (q), in the rhs of Eq. (11) has a general form  $\frac{2 e^2 d}{2} f$  (qd), where f (z) is a dimensionless function. Then the ISP contribution to  $\sim_2$  can be presented as

$$r_{2}(!) = \frac{4! E_{F}^{2} r_{s}^{2}}{(!)^{p} r_{s}^{2}} \frac{m d^{2}}{r^{2}} [f(0)]^{2} (!); \qquad (13)$$

where  $= \frac{2}{3E_F^2} \frac{R}{(2)^2} J_{pl}(!;q)$  is a dimensionless function of !, and we assumed that qd 1. For ISP contribution this assumption is justimed, since qd  $_0$  (k<sub>F</sub> d). Then, using Eq. (8), we obtain

pl 
$$\frac{0}{1+0}$$
 1  $\frac{! 2_{pl}(0)}{!_{pl}}^{2}$ ; (14)

where the width,  $!_{pl}$ , is given by ~  $!_{pl} = 2_0 (1 + _0)E_F$ . Note that  $_{pl}$  is non-zero only in the interval  $2_{pl}(0) < ! < 2_{pl}(0) + !_{pl}$ . Since this width  $!_{pl} \cdot E_F$ , we conclude that the plasm on peak constitutes a sharp feature on top of a wider two-electron band in ~\_2 (!).

The two-electron contribution to  $\sim_2$  (!) can be naturally divided into two frequency domains. First domain corresponds to the photon energy ! 2  $F_{\rm P}$ , as illustrated in Fig. 1. In this domain we still have qd 1, so that Eq. (13) applies but with calculated using  $J_{\rm ee}$  (!;q), de ned by Eq. (P). Upon performing the q-integration, we obtain

$$(t) = \frac{1}{\frac{2}{k_F^4}} \int_{k_1; k_2 < k_F}^{k_1} dk_1 dk_2 \frac{k_1 k_2 f}{2k_F^2} t; (15)$$

with t =  $(2 ~ ~!)=E_F$ . The function (t) evaluated num erically is plotted in Fig. 3 together with the asym ptotes (1 2t) fort 1 and (4  $2E_F^2=15$  for (2 t) 1. Singular points t = 2 and t = 0 correspond to excitation of two electrons from the bottom of the band and from the Ferm i level, respectively. It follows from Eqs. (14) and (15), that the ratio of two-plasm on and two-electron contributions is equal to  $_0(1 + _0)^{-1}$  1.

In the second dom ain, ! 2 &, two excited electrons have high energies. Thus, their momenta are almost opposite to each other, both having the absolute value of  $q_1 = \frac{1}{2m} (\sim ! 2) = \sim$ . Then the behavior of  $\sim_2 (!)$  in the high-frequency dom ain is given by Eq. (13) with  $[f(0)]^2$  replaced by  $[f(qd)]^2$ . Thus, this behavior is determined by the actual con nem ent potential prole. In the following we will consider the most com mon

example of a biased rectangular QW.

Biased rectangular QW W ithout bias, due to the QW symmetry, we have f(qd) = 0 for all q. In the presence of bias U . , which amounts to the perturbation U z=d of con ning potential, the size-quantization wave-functions in Eq. (1) acquire symmetry-breaking corrections,  ${}'_{1}(z) = {}'_{1}^{(0)}(z)$  (U  $z_{12} = d$ )  ${}'_{2}^{(0)}(z)$ , and  ${}'_{2}(z) = {}'_{2}^{(0)}(z) + (U z_{12} = d) {}'_{1}^{(0)}(z)$ , where  ${}'_{1}^{(0)}, {}'_{2}^{(0)}$  are the size-quantization wave functions at U = 0, while the subband separation remains  $=\frac{3^{-2}}{2m}\frac{d^2}{d^2}$ . Then a straightforward calculation yields f (qd) =  $\frac{U Z_{12}}{d}$ F (qd), where the function F (s) can be expressed analytically and has the following behavior: F (0) =  $595=144^{2}$ ; F (s) j 1 6=ŝ. Thus, the large-! behavior of  $\sim_2$  (!) is the following: ĵ<sup>2</sup> (! 2 f. This slow decay is il- $_{2}(!) / !=(!)$ lustrated in Fig. 3, where  $\sim_2$  (!), caluclated num erically for realistic parameters of quantum well, is plotted for three di erent electron concentrations. The relative oscillator strength for two-electron absorption is given by

Z d! ~<sub>2</sub> (!) = C 
$$\frac{r_s E_F U}{2}^2$$
: (16)

U sing the explicit form of F (s) we have num erically cal-

culated the coe cient C in Eq. (16) to be 8.2  $10^{-2}$ .

C oncluding rem arks | The lineshape of new peak is governed by three energy scales: sharp rise within the energy interval 2  $2E_F < \sim ! < 2$ , slow decay for  $\sim ! > 2$ , and a sharp two-ISP peak of the width  $gE_F^{3=2} = 1=2$  on the top of the two-electron band. This di erence in scales justi es the fact that we have disregarded the process of excitation of one ISP and one electron [this process is also captured by Eq. (4)]. The unusually sm all ISP contribution can be traced to the sm allness of the ISP e ectve m ass.

In general, the fact that a single photon can cause double ionization of an interacting system with a discrete spectrum (such as helium atom [14]) is known for almost four decades. A remarkable feature of quantum wells is that a sharp interaction-induced peak emerges in a system with continuous electron spectrum [15]. The necessary condition for observation of the two-electron absorption is that quantum well must be deep enough, namely deeper than 7 =3. O therwise, two-electron absorption will result in photoionization. The above condition is always satis ed for thick quantum wells. How ever, increasing the thickness has a side e ect that the num – ber of size-quatization levels in the well inceareses, thus com plicating the analysis of the absorption spectra. Note

nally, that although we considered the sim plest m odel of hom ogeneous electron gas at zero tem perature with two parabolic subbands, our theory can be easily generalized to the realistic situations [16, 17, 18, 19]. Im portant is that nonparabolicity, nite tem perature, disorder, etc. are not expected to suppress the two-electron absorption.

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